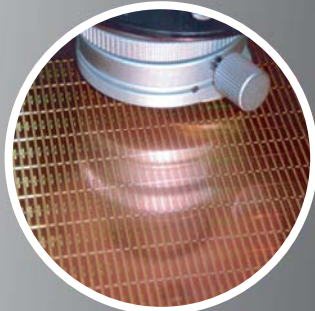


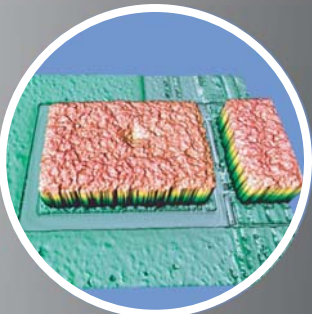
# CYBERSURF 3D

*Automatic and manual semiconductor process control*

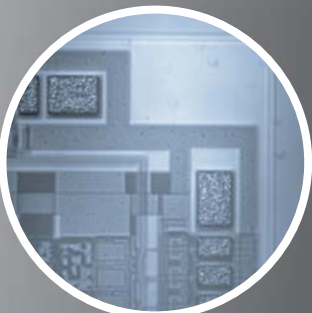
*Cybersurf 3D, a new concept of machine for fully automated control on silicon wafers*



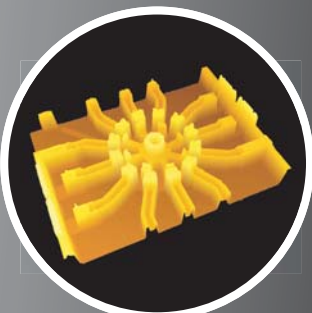
*Fully automatic wafer alignment*



*3D bump measurement result*



*Automatic chip alignment*



*MEMS micromotor  
static and dynamic characterization*



- **Automatic wafer load / unload**
- **6" and 8" wafers, 12" on request**
- **Auto alignment**
- **Automatic measurement sequence :**
  - . Bump dimensions
  - . Roughness (grinding, local stress)
  - . Step height
  - . Film thickness (photoresist, oxide,...)
- **Custom report format :**
  - . Chip per chip statistics
  - . Wafer per wafer statistics
  - . Evolution of process parameter with time over months

# Process metrology solution for wafer-level packaging

## WAFER THINNING

- > Flattness
- > Radius of curvature
- > Surface Roughness

## FILM THICKNESS AND TOPOGRAPHY

- > Photoresist, oxide, silicon nitride, ...
- > Homogeneity across wafer surface
- > Roughness
- > Apertures size

## BUMP CONTROL

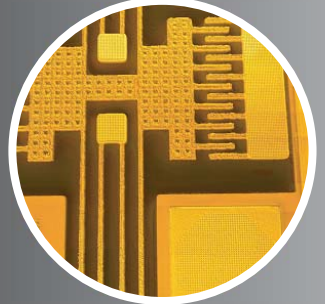
- > Bump size (Length, width, height)
- > Bump roughness
- > Bump defects
- > Wafer thickness measurement on individual or packaged chips

## AUTOMATIC WAFER LOAD / UNLOAD

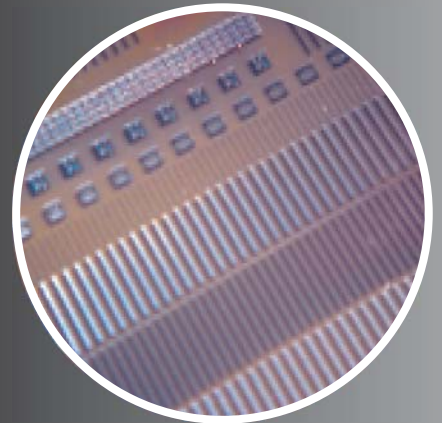
- > Compatible with manual or automated wafer loading
- > 6" and 8" compatible, automatic detection
- > Automatic wafer alignment
- > Wafer 12" (optional)
- > FOUP capable (optional)

## PERFORMANCE

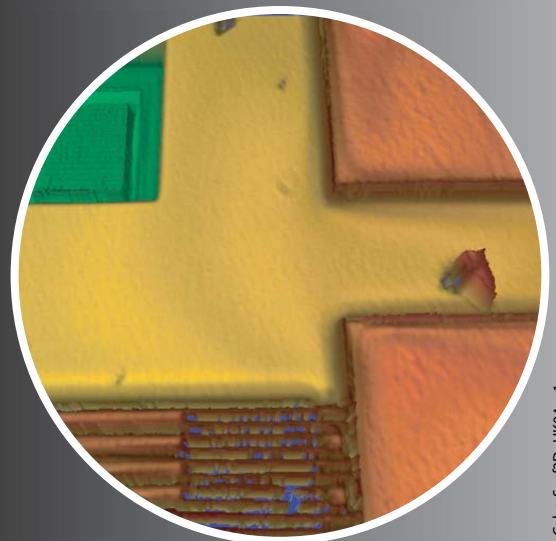
<b>Vertical measurement range</b>	0.1 nm to 500 $\mu\text{m}$ standard
<b>Vertical resolution</b>	< 1 Å
<b>RMS repeatability</b>	0.3 nm RMS
<b>Lateral spatial sampling</b>	0.1 to 9.3 $\mu\text{m}$
<b>Field of view</b>	7.2 mm to 80 $\mu\text{m}$
<b>Reflectivity</b>	1% to 100%



MEMS characterization



Structure size and defects characterisation, report sheet per chip and per wafer



Film thickness measurement